

FOR PTO-1449 (Modified)
LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANTS INFORMATION DISCLOSURE
STATEMENT

(Use several sheets if necessary)

ATTY. DOCKET NO.

3521.171

SERIAL NO.

10/287,864

APPLICANT
 SOMIT TALWAR, et al.

FILING DATE
 November 6, 2002

GROUP
 2881

REFERENCE DESIGNATION U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER							DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	A	4	9	0	8	4	9	3	3-13-90	Susemihl	219	121.67	
	B	4	3	5	6	3	7	5	10-26-82	Josephy, et al.	219	121 LH	
	C	6	3	6	6	3	0	8	4-2-02	Hawryluk, et al.	347	256	

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER							DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
													YES	NO

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

	D	Naem, Boothroyd, Calder, <i>CW Laser Annealed Small-Geometry NMOS Transistors</i> , Mat. Res. Soc. Symp. Proc. Vol. 23 (1984) pp 229-234.
	E	Goetzlich, Tsien, Ryssel, <i>Relaxation Behavior of Metastable AS and P Concentrations in SI After Pulsed and CW Laser Annealing</i> , Mat. Res. Soc. Symp. Proc. Vol. 23 (1984) pp 235-240

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.